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 Amendment dated October 15, 2008
 Examiner BRADLEY, Matthew A.

 Response to Office Action of July 22, 2008
 TC/A,U, 2187

Amendments to the Claims

This listing of claims will replace all prior versions, and listings, of claims in the

application:

1. (Currently Amended) A non-volatile memory comprising:

an array of non-volatile memory cells; and

a stack controller coupled to receive an address and to determine an appropriate

address for accessing values in a stack stored in a subset of the array of non-volatile

memory cells, the stack having a stack depth configured in a nonvolatile memory to store

parameter values, where each memory write invalidates previous data and further

wherein the stack controller increments updates a pointer to a first valid word in the

stack, the stack controller to maintain the stack utilizing two blocks of the non-volatile

memory cells and to cause a first block to be erased when each word within the first

block is invalid and the values in the stack are stored in a second block of the non-volatile

memory.

2. (Previously Presented) The non-volatile memory of claim 1 wherein the

first block and the second block are erased independently.

3-4. (Canceled)

(Currently Amended) The non-volatile memory of claim 1, the stack

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controller further including a register to store an offset value used to generate an address for words in the nonvolatile memory.

## (Canceled) 6.

7. (Previously Presented) The non-volatile memory of claim 1, wherein the stack controller is configured to distribute write cycles across multiple blocks of the nonvolatile memory.

## 8-10. (Canceled)

11. (Currently Amended) A method to manage a stack in a non-volatile memory having an array of cells logically organized as blocks, the method comprising: receiving an address corresponding to an access to the stack;

maintaining a nonvolatile stack to store parameter values in words of a nonvolatile memory where a write of the nonvolatile stack invalidates previous instructions or data stored in the nonvolatile stack;

incrementing updating a pointer to a first valid word in the stack maintaining the stack utilizing two blocks of the non-volatile memory cells and to cause a first block to be erased when each word within the first block is invalid and the values in the stack are stored in a second block of the non-volatile memory.

12. (Previously Presented) The method of claim 11 wherein a memory pool in at least first and second blocks of the nonvolatile memory are sized to balance cycling and data retention capabilities with a write specification.

- (Previously Presented) The method of claim 11 further comprising distributing write cycles across multiple blocks of the nonvolatile memory.
- (Previously Presented) The method of claim 11 wherein the nonvolatile memory maps a received address to determine memory blocks to be written.
  - 15-31. (Canceled)
- (Previously Presented) The stack of claim 1 wherein the nonvolatile memory is a polymer memory that includes ferroelectric memory cells.